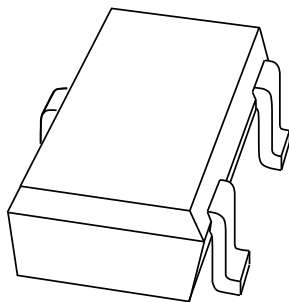


DATA SHEET



BAP64-06W Silicon PIN diode

Product specification
Supersedes data of 2001 Feb 02

2001 Apr 17



Silicon PIN diode

BAP64-06W

FEATURES

- High voltage, current controlled
- RF resistor for RF attenuators and switches
- Low diode capacitance
- Low diode forward resistance
- Low series inductance
- For applications up to 3 GHz.

APPLICATIONS

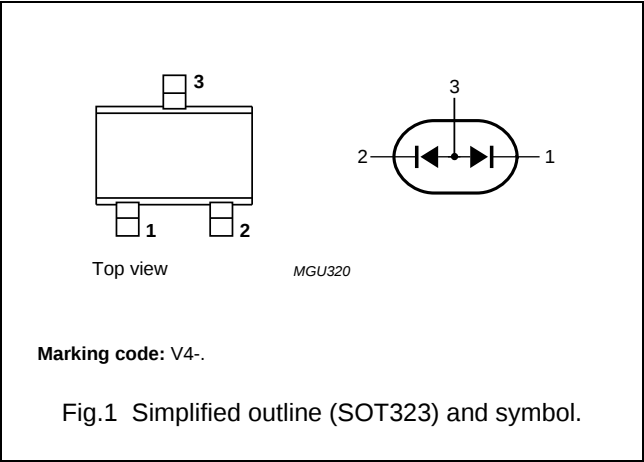
- RF attenuators and switches.

DESCRIPTION

Two planar PIN diodes in common anode configuration in a SOT323 small SMD plastic package.

PINNING

PIN	DESCRIPTION
1	cathode 1
2	cathode 2
3	common connection



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per diode					
V_R	continuous reverse voltage		–	100	V
I_F	continuous forward current		–	100	mA
P_{tot}	total power dissipation	$T_s = 90\text{ }^{\circ}\text{C}$	–	240	mW
T_{stg}	storage temperature		–65	+150	$^{\circ}\text{C}$
T_j	junction temperature		–65	+150	$^{\circ}\text{C}$

Silicon PIN diode

BAP64-06W

ELECTRICAL CHARACTERISTICST_j = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
Per diode					
V _F	forward voltage	I _F = 50 mA	0.95	1.1	V
I _R	reverse current	V _R = 100 V	–	10	μA
		V _R = 20 V	–	1	μA
C _d	diode capacitance	V _R = 0; f = 1 MHz	0.52	–	pF
		V _R = 1 V; f = 1 MHz	0.37	–	pF
		V _R = 20 V; f = 1 MHz	0.23	0.35	pF
r _D	diode forward resistance	I _F = 0.5 mA; f = 100 MHz; note 1	20	40	Ω
		I _F = 1 mA; f = 100 MHz; note 1	10	20	Ω
		I _F = 10 mA; f = 100 MHz; note 1	2	3.8	Ω
		I _F = 100 mA; f = 100 MHz; note 1	0.7	1.35	Ω
S ₂₁ ²	isolation	V _R = 0; f = 900 MHz	18.5	–	dB
		V _R = 0; f = 1800 MHz	13.5	–	dB
		V _R = 0; f = 2450 MHz	10.9	–	dB
S ₂₁ ²	insertion loss	I _F = 0.5 mA; f = 900 MHz	1.86	–	dB
		I _F = 0.5 mA; f = 1800 MHz	2.06	–	dB
		I _F = 0.5 mA; f = 2450 MHz	2.23	–	dB
S ₂₁ ²	insertion loss	I _F = 1 mA; f = 900 MHz	1.01	–	dB
		I _F = 1 mA; f = 1800 MHz	1.06	–	dB
		I _F = 1 mA; f = 2450 MHz	1.10	–	dB
S ₂₁ ²	insertion loss	I _F = 10 mA; f = 900 MHz	0.19	–	dB
		I _F = 10 mA; f = 1800 MHz	0.21	–	dB
		I _F = 10 mA; f = 2450 MHz	0.27	–	dB
S ₂₁ ²	insertion loss	I _F = 100 mA; f = 900 MHz	0.08	–	dB
		I _F = 100 mA; f = 1800 MHz	0.10	–	dB
		I _F = 100 mA; f = 2450 MHz	0.16	–	dB
τ _L	charge carrier life time	when switched from I _F = 10 mA to I _R = 6 mA; R _L = 100 Ω; measured at I _R = 3 mA	1.55	–	μs
L _S	series inductance	I _F = 100 mA; f = 100 MHz	1.6	–	nH

Note

1. Guaranteed on AQL basis: inspection level S4, AQL 1.0.

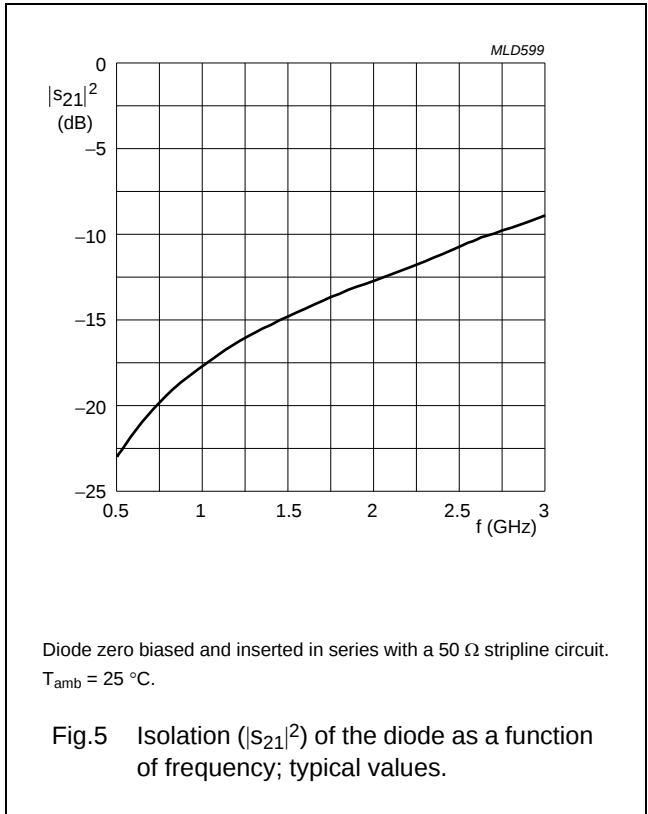
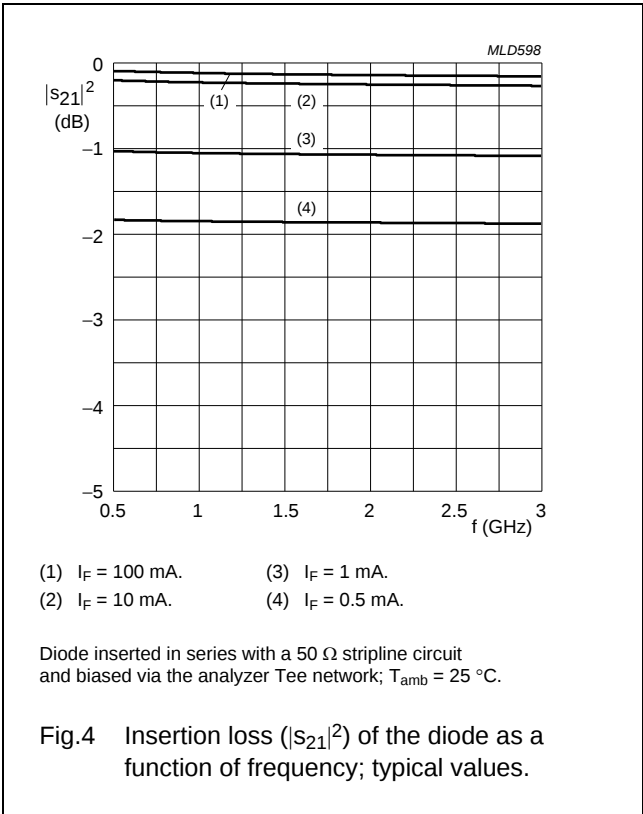
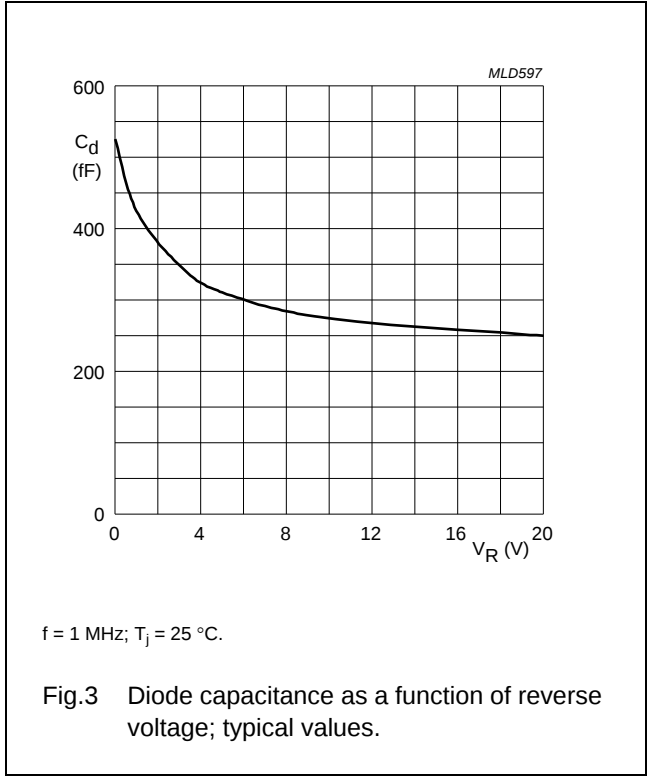
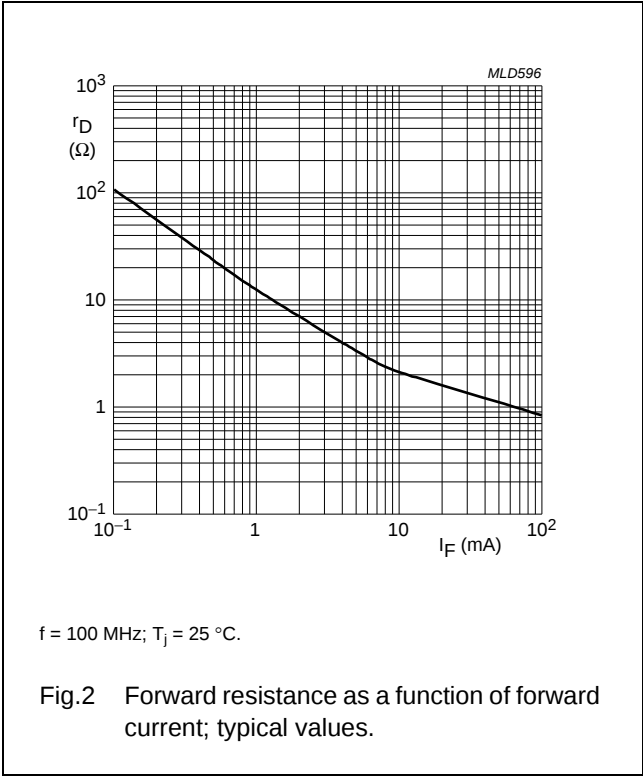
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-s}	thermal resistance from junction to soldering point	250	K/W

Silicon PIN diode

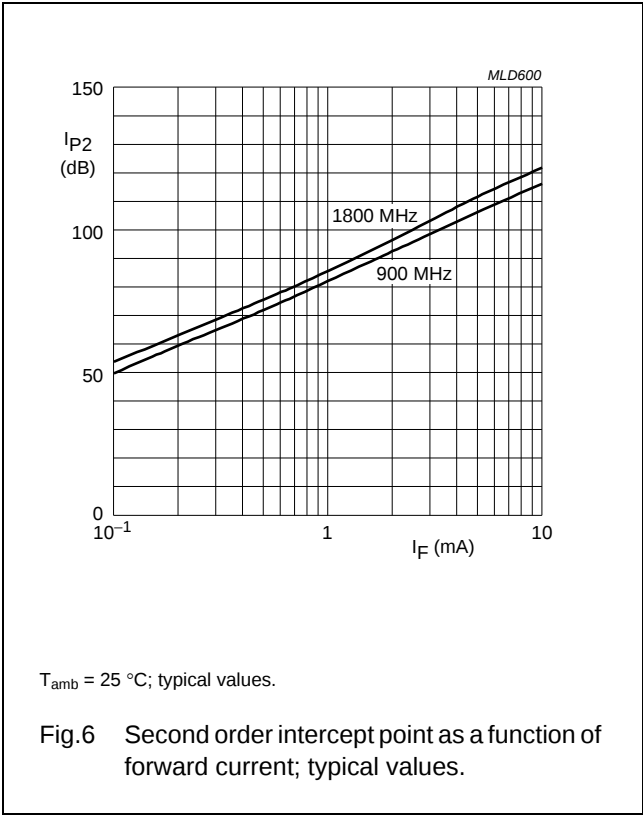
BAP64-06W

GRAPHICAL DATA



Silicon PIN diode

BAP64-06W



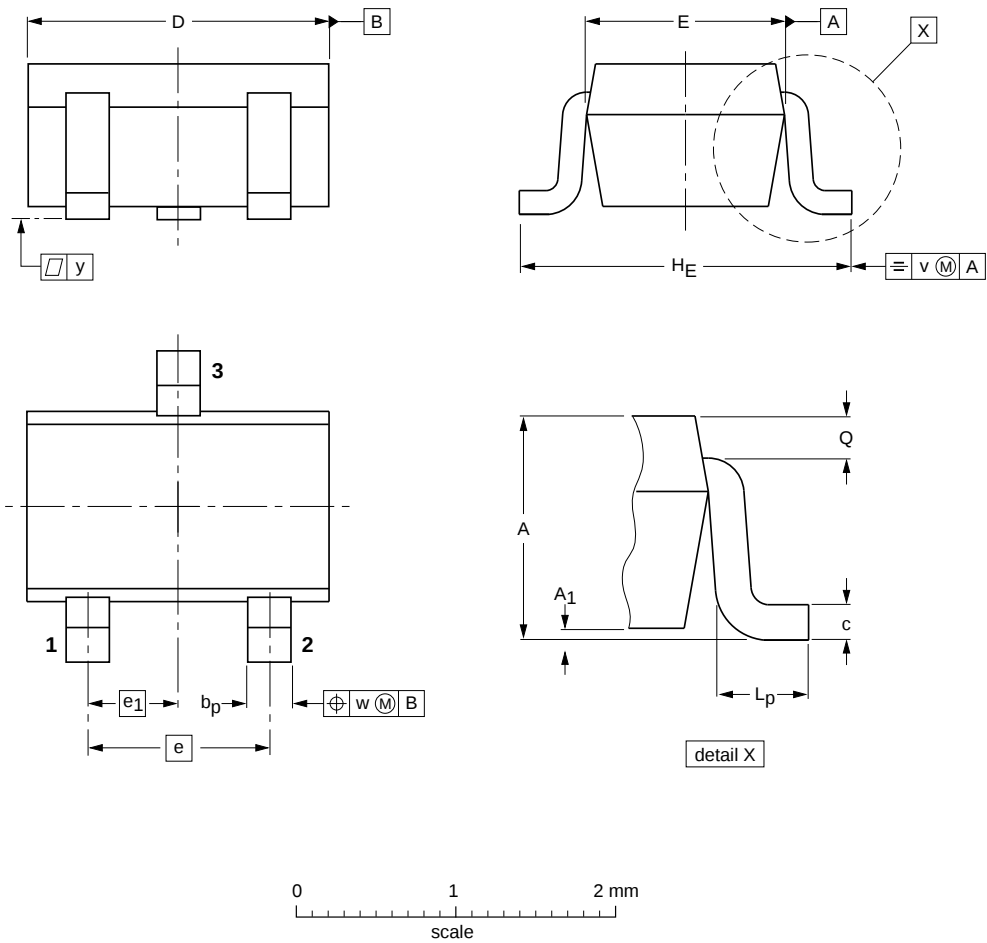
Silicon PIN diode

BAP64-06W

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT323



DIMENSIONS (mm are the original dimensions)

UNIT	A	A1 max	bp	c	D	E	e	e1	HE	Lp	Q	v	w
mm	1.1 0.8	0.1	0.4 0.3	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT323			SC-70			04-11-04 06-03-16

Silicon PIN diode

BAP64-06W

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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Contact information

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Printed in The Netherlands

R77/02/pp9

Date of release: 2001 Apr 17